



Product data sheet

1. General description

Hyperfast power diode (Bare die without sawn).

2. Features and benefits

- Low Forward Voltage Drop
- Low leakage current
- Fast reverse recovery
- Bare die

3. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values		Unit	
V_{RRM}	repetitive peak reverse voltage		[1]		600		V
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse	[2]		30		А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static characteristics							
$V_{\rm F}$	forward voltage	I _F = 30 A; T _j = 25 °C	[2]	-	2.00	2.75	V
Dynamic characteristics							
t _{rr}	reverse recovery time	I_{F} = 1 A; V_{R} = 30 V; dI_{F}/dt = 50 A/µs; T_{j} = 25 °C	[2]	-	-	35	ns

4. Ordering information

Table 2. Ordering information						
Product type	Orderable part number	Description	Packing method			
WB30FC60AL	WB30FC60ALZ	Bare die on wafer	Unsawn wafer, Vacuum packing			

5. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage		[1]	600	V
V _{RWM}	crest working reverse voltage		[1]	600	V
V _R	reverse voltage	DC	[1]	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse	[2]	30	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 µs; square-wave pulse	[2]	60	А
1.0111	non-repetitive peak forward	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	[2]	200	А
	current	$t_{\rm p}$ = 8.3 ms; $T_{j(\text{init})}$ = 25 °C; sine-wave pulse	[2]	220	А
Tj	junction temperature			-40 to 175	°C

6. Characteristics

	naracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
V _F	forward voltage	I _F = 30 A; T _j = 25 °C	[2]	-	2.00	2.75	V
		I _F = 30 A; T _j = 150 °C	[2]	-	1.38	1.80	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	[1]	-	-	10	μA
		V _R = 600 V; T _j = 150 °C	[2]	-	-	600	μA
Dynamic	characteristics						
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	-	35	ns
		$I_F = 30 \text{ A}; V_R = 200 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	[2]	-	-	35	ns

Notes:

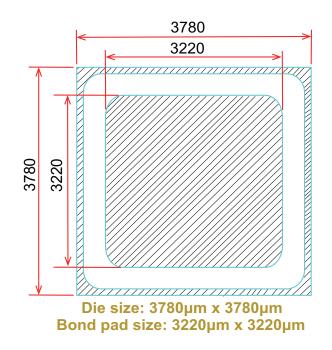
 [1] means that parameter are 100% test at T_{amb} = 25°C.
[2] means that the guaranteed ratings and parameter limits will depend on the assembled structure. When correctly assembled with suitable die bonding and wire bonding, the device will have ratings and characteristics guaranteed in this data sheet, similar to the assembled devices.

WB30FC60AL

Hyperfast power diode - Bare die

MECHANICAL SPECIFICATIONS			
Chip size	3.78 x 3.78	mm ²	
Anode pad size	3.22 x 3.22	mm ²	
Area total / active	14.28 / 10.37	mm ²	
Thickness	300	μm	
Wafer size	125	mm	
Max possible chips per wafer	761	pcs	
Passivation	Glass / Trough		
Front metal	AI		
Back metal	Ti Ni Ag		

CHIP LAYOUT



WB30FC60AL

Hyperfast power diode - Bare die

7. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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